# Lection 2

#### Excitons in external fields (1h)

(bulk exciton in a magnetic field, Zeeman effect, diamagnetic shift; exciton in an electric field, Stark effect, the exciton in QW in external fields, confined stark effect; case of the degenerate valence band; Pockels effect)

## **Exciton in magnetic fields**

(simple band structure)

In magnetic field we have to change  $\mathbf{p} \rightarrow \mathbf{p} + \frac{e}{c} \mathbf{A}$  obtain

$$\begin{bmatrix} -\frac{\hbar^2 \nabla_e^2}{2m_e} - \frac{\hbar^2 \nabla_h^2}{2m_h} - \frac{e^2}{\varepsilon r_{eh}} - \frac{ie\hbar}{m_e c} A(\mathbf{r}_e) \nabla_e + \frac{ie\hbar}{m_h c} A(\mathbf{r}_h) \nabla_h + \frac{e^2}{2m_e c^2} A^2(\mathbf{r}_e) + \frac{e^2}{2m_h c^2} A^2(\mathbf{r}_h) \end{bmatrix} \Psi(\mathbf{r}_e, \mathbf{r}_h) = E \Psi(\mathbf{r}_e, \mathbf{r}_h)$$

Relative motion and center of mass motion

$$-i\hbar\nabla_{e} = \left(-i\hbar\nabla + \frac{e}{c}\vec{A}(\vec{r}) + \alpha\hbar\vec{Q}\right) \qquad -i\hbar\nabla_{h} = \left(i\hbar\nabla + \frac{e}{c}\vec{A}(\vec{r}) + \beta\hbar\vec{Q}\right)$$

Take the trial function in the form

$$\Psi\left(\vec{R},\vec{r}\right) = \exp\left\{i\left[\vec{Q} - \frac{e}{\hbar c}\vec{A}\left(\vec{r}\right)\right]\vec{R}\right\}F\left(\vec{r}\right)$$

For  $F(\vec{r})$  get equation



$$\frac{m_0}{m_e^*} \sim 10 \qquad \Longrightarrow \qquad \mu_{spin} = \frac{e}{mc}, \quad \mu_{orbit} \propto 10 \mu_{spin}$$

# The term $\vec{A} \cdot \vec{Q}$ Is magneto Stark effect $\frac{2e\hbar}{(m_e + m_h)c} \mathbf{A}(\mathbf{r}) \cdot \mathbf{Q} = \frac{e\hbar}{Mc} [\mathbf{Q} \times \mathbf{B}] \cdot \mathbf{r} = \frac{e}{c} [\mathbf{v} \times \mathbf{B}] \cdot \mathbf{r}$ $\frac{e}{c} [\mathbf{v} \times \mathbf{B}]$ Is the Lorentz force

It can be compensate by an electric field  $\mathbf{E}$  because

$$\left(\mathbf{E} + \frac{e}{c} [\mathbf{v} \times \mathbf{B}]\right) \cdot \mathbf{r}$$

The correction to energy is in the second order perturbation

$$\propto Q^2$$
 and  $\propto B^2$  Corrections to effective mass and diamagnetic shift



Magneto-Stark effect in CdS crystal in magnetic fields (Thomas Hopfield Phys. Rev. Lett. 5, 505 (1960))

# **In magnetic fields**

Additionally to spin magnetism 1). Orbital magnetism on *p* states 2). Diamagnetic shift 3). Magneto-Stark effect

# **Exciton in magnetic fields**

#### (cubic Td crystal)

$$H_{exc} = H_{ex}(0) + H_{ex}(B) + H_{ex}(K) + H_{ex}(K \cdot B) + H_{ex}(K^{2}) + H_{ex}(B^{2}) + \dots$$

Here:  $H_{ex}(0)$  exciton Hamiltonian in zero field and zero K

$$H_{ex}(B) = g_{e}\mu_{B}(\mathbf{\sigma} \cdot \mathbf{B}) - 2\mu_{B}\left[\hat{k}(\mathbf{J} \cdot \mathbf{B}) + \hat{q}(B_{x}J_{x}^{3} + B_{y}J_{y}^{3} + B_{z}J_{z}^{3})\right]$$

linear in magnetic field contribution

$$H_{ex}(K) = C \left[ K_{x} J_{x} \left( J_{y}^{2} - J_{z}^{2} \right) + K_{y} J_{y} \left( J_{z}^{2} - J_{x}^{2} \right) + K_{z} J_{z} \left( J_{x}^{2} - J_{y}^{2} \right) \right]$$

linear in wave vector contribution

$$H_{ex}(KB) = A_1 \left[ B_x H_x \left( J_y^2 - J_z^2 \right) + c.p. \right] + A_2 \left( \left[ \mathbf{B} \mathbf{K} \right]_x \left\{ J_y \cdot J_z \right\} + c.p. \right) \right]$$

bilinear in magnetic field and wavevector term

$$H(K^{2}) = \frac{\alpha^{2}}{2m_{e}}K_{z}^{2}I + \frac{\beta^{2}}{2m_{0}}\left(\gamma_{1} + \frac{5}{2}\gamma\right)K_{z}^{2}I - \frac{\gamma}{m_{0}}\beta^{2}(K_{z}J_{z})^{2}$$

exciton in the absence of magnetic field

## **Exciton in magnetic fields**

(complex band structure) Exciton Hamiltonian

$$H = \hbar^{2} \mathbf{K}_{e}^{2} / 2m_{e} - \frac{\hbar^{2}}{2m_{0}} [(\gamma_{1} + \frac{5}{2}\gamma)\mathbf{K}_{h}^{2}\mathbf{I} - 2\gamma(\vec{J}\mathbf{K}_{h})^{2}] - \frac{e^{2}}{\kappa |\vec{r}_{e} - \vec{r}_{h}|}$$
$$-i\hbar \nabla_{e} = \left(-i\hbar \nabla + \frac{e}{c}\mathbf{A}(\vec{r}) + \alpha\hbar \mathbf{Q}\right) \qquad -i\hbar \nabla_{h} = \left(i\hbar \nabla + \frac{e}{c}\mathbf{A}(\vec{r}) + \beta\hbar \mathbf{Q}\right)$$

Because of the complex band structure we can not separate internal motion and center of mass motion in Faraday geometry we always have the term:

$$\frac{\beta\hbar\gamma}{m_0} [(\mathbf{p}_x + \frac{e}{c}A_x)J_x + (\mathbf{p}_y + \frac{e}{c}A_y)J_y](Q_zJ_z)$$

This term mixed 1*s* ground state and all *p* states of the internal motion and leads to two effects for <u>moving exciton</u>:

#### 1) Increase exciton Zeeman splitting



$$\mathcal{E}_{1S}^{(2)}(Q,B) = 2SB_z Q_z^2 (7J_z - 4J_z^3)$$

$$S = \left(\frac{\gamma}{m_0}\right)^2 \hat{\beta}^2 \left(\frac{e\hbar}{c}\right) \left(\frac{\hbar^2}{2} \frac{1}{Ry^*}\right) \sum_{n=2}^{\infty} \frac{\langle 1S | r/a_B | nP \rangle \langle 1S | a_B \nabla | nP \rangle}{1 - 1/n^2 + \Delta(Q)/Ry^*}$$



$$\mathcal{E}_d(B,Q) = D_1 Q_z^2 B^2 \mathbf{I}$$

$$D_1 = \frac{3}{4} \left(\frac{\gamma}{m_0}\right)^2 \hat{\beta}^2 \left(\frac{e\hbar}{c}\right)^2 \left(\frac{1}{Ry^*}\right) a_B^2 \sum_n \frac{\left|\left\langle 1S \left| r \right/ a_B \left| nP_y \right\rangle \right|^2}{1 - 1/n^2 + \Delta(Q)/Ry^*}\right|$$

These effects are present in narrow wells also and in QDs and in NWs

#### In the case of degenerate valence band

Due to mixing of internal and center of mass motion 1). Zeeman splitting 2). Diamagnetic shift depend on the center of mass energy

# Effect of parity in the exciton spectra



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QUANTIZATION OF EXCITONIC POLARITONS IN CdTe-CdZnTe DOUBLE HETEROSTRUCTURES

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#### **Faraday geometry**

Linear in wave vector and magnetic field contribution in bulk  $T_d$ 

$$H_{ex}(KH) = B_1\left[K_xH_x(J_y^2 - J_z^2) + c.p.\right]$$

In  $D_{2d}$  similar

consider the first term

$$B_1 K_z H_z \times \begin{bmatrix} 0 & 0 & \sqrt{3} & 0 \\ 0 & 0 & 0 & \sqrt{3} \\ \sqrt{3} & 0 & 0 & 0 \\ 0 & \sqrt{3} & 0 & 0 \end{bmatrix}$$

Mixing of HH and LH excitons

$$(\mathcal{E}_{HH}^{0} - \hbar \omega) |x_{HH}\rangle + i\mu g_{HH} H_{z} |y_{HH}\rangle = d_{x}E_{x} + BH_{z} \frac{1}{3} \frac{d_{x}}{\left|\mathcal{E}_{LH}^{0} - \mathcal{E}_{HH}^{0}\right|} i\nabla_{z}E_{x}$$

$$(\mathcal{E}_{HH}^{0} - \hbar \omega) |y_{HH}\rangle - i\mu g_{HH} H_{z} |x_{HH}\rangle = d_{y} E_{y} - B H_{z} \frac{1}{3} \frac{d_{y}}{\left|\mathcal{E}_{LH}^{0} - \mathcal{E}_{HH}^{0}\right|} i \nabla_{z} E_{y}$$

Reflectivity spectrum taken from GaAs/AlGaAs QW at zero magnetic field

Incident light is linearly polarized in (100), circular polarized component is analyzed



Redistribution of exciton oscillator strength between odd and even states

Incident light is linearly polarized, circular polarization is analyzed



Voigt geometry Cubic crystal  $B_{2}\left(\left\lceil \vec{H}\vec{K} \right\rceil_{v} \left\{ J_{y} \cdot J_{z} \right\} + \left[ \vec{H}\vec{K} \right]_{v} \left\{ J_{x} \cdot J_{z} \right\} \right)$  $\left\{J_{y}J_{z}\right\} = \begin{vmatrix} 0 & -i\sqrt{3} & 0 & 0 \\ i\sqrt{3} & 0 & 0 & 0 \\ 0 & 0 & 0 & i\sqrt{3} \\ 0 & 0 & -i\sqrt{3} & 0 \end{vmatrix}$  $\{J_x J_z\} = \begin{bmatrix} 0 & \sqrt{3} & 0 & 0 \\ \sqrt{3} & 0 & 0 & 0 \\ 0 & 0 & 0 & -\sqrt{3} \\ 0 & 0 & -\sqrt{3} & 0 \end{bmatrix}$ 

# Voigt geometry

Magnetic field inversion effect



#### Voigt geometry Wurzite crystal

For the conductivity band

$$H_{\Gamma_{7}}(\mathbf{k},\mathbf{H}) = \left(E_{\Gamma_{7}}^{0} + \frac{\hbar^{2}k_{z}^{2}}{2m_{II}} + \frac{\hbar^{2}k_{\perp}^{2}}{2m_{\perp}}\right)\hat{I} + a[\mathbf{H} \times \mathbf{k}]_{z}\hat{I} + b(\sigma_{x}k_{y} - \sigma_{y}k_{x}) + \frac{1}{2}\mu(g_{II}H_{z}\sigma_{z} + g_{\perp}(\mathbf{H}_{\perp} \cdot \boldsymbol{\sigma}_{\perp}))$$

For the valence band

$$H_{\Gamma_9}(\mathbf{k},\mathbf{H}) = \left(E_{\Gamma_9}^0 - \frac{\hbar^2 k_z^2}{2m_{II}} - \frac{\hbar^2 k_\perp^2}{2m_\perp}\right)\hat{I} + a_1[\mathbf{H} \times \mathbf{k}]_z\hat{I} + d_1\sigma_x(k_x^3 - 3k_xk_y^2) + d_2\sigma_y(3k_x^2k_y - k_y^3) + \frac{1}{2}\mu g_{II}H_{II}$$

optical transitions

$$\left|D_{v}+\kappa_{y}Q_{v}\right|^{2}$$
 and  $\left|D_{v}-\kappa_{y}Q_{v}\right|^{2}$ 

#### Effect of magnetic field inversion



Transmission spectra of CdS in magnetic field of 3.1T, H is perpendicular to  $C_6$  axis

#### Effect of inversion of magnetic field



#### In the structures without inversion symmetry

 Effect of "parity" (due to nonreciprocal magnetic field induced birefringence)
 "Effect of inversion of magnetic field"

#### **Quantum confined Stark effect**

Lateral electric field  $F \parallel (x, y)$ 

Two effects: 1) current, 2) dissociation of the exciton Broadening of the exciton level  $-\ln\Gamma \propto \frac{\Delta x}{a_B} \propto \frac{E_B}{|e|F_{\parallel}a_B}$ 

Transverse field  $F \perp (x, y)$ 

No dissociation, but Stark shift

$$\Delta E_{exc} = \delta E_{e1} + \delta E_{h1} - \delta \varepsilon \qquad \delta E_1 = -\sum_{n \neq 1} \frac{(eF \, z_{n1})^2}{E_n - E_1} \propto -0.01 \frac{(eFd)^2}{E_1}$$



#### **Stark effect in superlattice**

In the tight binding model we have equation

 $IC_{n-1} + E_0C_n + IC_{n+1} = EC_n$ E - Energy, I - transfer integral For the Bloch solutions:  $C_n = \exp(iK_z dn)$  miniband:  $E(K_z) = E_0 + 2I\cos K_z d$ The miniband width equal  $\Delta = 4I$ Effective mass  $M = \frac{\hbar^2}{2|I|d^2}$ 

In the presence of electric field tight binding equation

$$I(C_{n-1} + C_{n+1}) + (E_0 + |e| Fdn)C_n = 0$$

The electric field just shifts the energy  $E_0$ 

When the detuning |e|Fd becomes bigger the miniband width  $\Delta$ LOCALIZATION

Localization length 
$$L \approx$$

$$L \approx \frac{\Delta}{\left| e \right| F}$$

# **Wannier Stark localization**



#### **Wannier Stark localization**



# **In superlattices** Wannier-Stark localization

# **Quantum confined Pockels effect**

(Linear in electric field Birefringence)

Dielectric function

 $\mathcal{E}_{ii}(\omega, \mathbf{k}, \mathbf{E}) = \mathcal{E}_{ii}(\omega) + i\gamma_{iil}(\omega)k_l + A_{iil}(\omega)E_l + B_{iilm}(\omega)k_lk_m + C_{iilm}(\omega)E_lE_m + D_{iilm}(\omega)k_lE_m + \dots$  $\mathcal{E}_{ii}(\omega)$  normal frequency dispersion  $\gamma_{iil}(\omega)k_l$  natural optical activity (gyrotropy)  $A_{iil}(\omega)E_l$  Pockels effect  $B_{iilm}(\omega)k_{l}k_{m}$  spatial dispersion due to exciton motion  $C_{iilm}(\omega)E_lE_m$  Kerr effect  $D_{iilm}(\omega)k_{l}E_{m}$  electric field induced gyrotropy

#### 1). Bulk mechanism

$$\boldsymbol{\varepsilon}_{ij}\left(\boldsymbol{\omega}, \mathbf{E}, \mathbf{K}\right) = \boldsymbol{\varepsilon}_{ij}^{0}\left(\boldsymbol{\omega}, \mathbf{K}\right) + A_{ijl}\left(\boldsymbol{\omega}, \mathbf{K}\right) \boldsymbol{E}_{l}$$
$$\boldsymbol{\delta}\boldsymbol{\varepsilon}_{ij}\left(\boldsymbol{E}\right) = \begin{bmatrix} 0 & A\boldsymbol{E}_{z} & 0\\ A\boldsymbol{E}_{z} & 0 & 0\\ 0 & 0 & 0 \end{bmatrix}$$

**Linear birefringence** 

#### 2) Interface mechanism

Bloch functions for the valence band  $\Gamma_8$  are

$$\begin{aligned} \left| \Gamma_{8}, 3/2 \right\rangle &= \frac{1}{\sqrt{2}} (X + iY) \uparrow \\ \left| \Gamma_{8}, 1/2 \right\rangle &= \frac{1}{\sqrt{6}} \Big[ 2Z \uparrow -(X + iY) \uparrow \Big] \\ \left| \Gamma_{8}, -1/2 \right\rangle &= \frac{1}{\sqrt{6}} \Big[ 2Z \downarrow +(X - iY) \downarrow \Big] \\ \left| \Gamma_{8}, -3/2 \right\rangle &= \frac{1}{\sqrt{2}} (X - iY) \downarrow \end{aligned}$$

#### **Boundary conditions**

We can expand an arbitrary wave function in the heterostructure in the set of these functions

$$\Psi = \sum_{i=1} F_i(r) \big| \Gamma_8, i \big\rangle$$

In a heterostructure we need boundary conditions

1). Continuity of the wavefunction  $\mathbf{F}_A = \mathbf{F}_B$ 

2). Continuity of flax  $(\hat{v}_z \mathbf{F})_A = (\hat{v}_z \mathbf{F})_B$ 

$$\hat{\mathbf{v}}$$
 - Velocity operator  $\hat{v} \equiv \frac{1}{\hbar} \frac{\partial \hat{H}}{\partial K}$ 

#### Symmetry of a normal quantum well

 $D_{2d}: C_2, 2S_4, 2U_2, 2\sigma_d$ 



Рис. 4.5. Группа D<sub>2d</sub>



Symmetry of a real interface In QWs based on zinc blend type semiconductors

 $C_{2v}: C_2, \sigma_1, \sigma_2$ 

Boundary conditions taking into account low interface symmetry for valence band  $\Gamma_8$ 

$$\begin{pmatrix} F_j \end{pmatrix}_A = \begin{pmatrix} F_j \end{pmatrix}_B \\ \left( \nabla^j F_j \right)_A = \left( \nabla^j F_j \right)_B + \frac{2}{\sqrt{3}} t_{LH} \left\{ J_x J_y \right\}_{jj'} F_{j'} \\ \nabla^{\pm 3/2} \equiv a_0 \frac{m_0}{m_{hh}} \frac{\partial}{\partial z}, \quad \nabla^{\pm 1/2} \equiv a_0 \frac{m_0}{m_{lh}} \frac{\partial}{\partial z}$$

Wave function for electrons  $\psi_{\pm 1/2}^{e_1} = K(z) |\Gamma_6, \pm 1/2\rangle$ 

Hole wavefunction from the boundary conditions

$$\psi_{\pm 3/2}^{hh1} = F(z) \left| \Gamma_8, \pm 3/2 \right\rangle \pm i G(z) \left| \Gamma_8, \mp 1/2 \right\rangle$$

Inside the well  

$$F(z) = A \cos k_h z + B \sin k_h z$$

$$G(z) = C \cos k_l z + D \sin k_l z$$

In barriers  

$$F(z) = F(\pm a/2) \exp\left[-\kappa_h(|z| - a/2)\right]$$

$$G(z) = G(\pm a/2) \exp\left[-\kappa_h(|z| - a/2)\right]$$

here 
$$k_{h} = \left(2m_{hh}^{A}\mathcal{E}/\hbar^{2}\right)^{1/2}, k_{l} = \left(2m_{lh}^{A}\mathcal{E}/\hbar^{2}\right)^{1/2}$$
$$\kappa_{h} = \left[2m_{hh}^{B}\left(V-\mathcal{E}\right)/\hbar^{2}\right]^{1/2}, \quad \kappa_{l} = \left[2m_{lh}^{B}\left(V-\mathcal{E}\right)/\hbar^{2}\right]^{1/2}$$

Satisfying the boundary conditions we found F(z) and G(z)

Transitions  $(e_{1},-1/2;h_{1},+3/2)$  and  $(e_{1},+1/2;h_{1},-3/2)$  are optically allowed

Matrix element of the transition in linear polarization

$$\left|M_{-1/2,3/2}(\mathbf{e})\right|^{2} = \left|M_{1/2,-3/2}(\mathbf{e})\right|^{2} = M_{0}^{2} \left(I_{1}^{2} + \frac{1}{3}I_{2}^{2} + \frac{2}{\sqrt{3}}I_{1}I_{2}\cos 2\phi\right)$$

$$\phi = 0, (\mathbf{e} \parallel (110)), \quad \phi = \pi / 2, (\mathbf{e} \parallel (1-10))$$

$$I_1 = \int K(z)F(z)dz$$
  $I_2 = \int K(z)G(z)dz$ 

Degree of linear polarization

$$\rho = \frac{\alpha_{(110)} - \alpha_{(1-10)}}{\alpha_{(110)} + \alpha_{(1-10)}} = \frac{2}{\sqrt{3}} \frac{I_1 I_2}{I_1^2 + (I_2^2 / 3)} \approx \frac{2}{\sqrt{3}} \frac{I_2}{I_1}$$

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Fig. 3.13. Polarization-resolved absorption spectra of the  $In_xGa_{1-x}As/InP$  sample in the region of e1-hh2 and e1-lh1 transitions. Figures (a)-(d) correspond to different fields. The incident light is polarized along the [110] (gray curves) and [110] (black curves) eigenaxes of the sample. Continuous lines display experimental data, whereas simulation results are represented by dashed lines. [3.69]

#### **Giant Pockels effect**



**Giant quantum confined Pockels effect** Due to interface anisotropy

#### summary

- 1). Orbital magneton is 10 times larger the spin ones.
- 2). In Mixing of the center of mass motion and relative motion cal strongly modify Zeeman effect and diamagnetic shift.
- 3). In the structures without inversion symmetry there is effect of "parity".
- 4). Electric field can leads to localization.
- 5). Giant Pockels effect due to interfaces.

## Literature

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